

Vishay Siliconix

N-Channel 150-V (D-S) MOSFET

| PRODUCT SUMMARY | | | | |
|---------------------|--|--------------------|--|--|
| V _{DS} (V) | R_{DS(on)} (Ω) | I _D (A) | | |
| 150 | 0.050 at V _{GS} = 10 V | 5.0 | | |

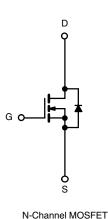
FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFETs
- Compliant to RoHS Directive 2002/95/EC



FREE Available

SO-8 S D 1 8 D S 7 2 S D 6 3 G D 4 5 Top View



Ordering Information: Si4488DY-T1-E3 (Lead (Pb)-free) Si4488DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

| ABSOLUTE MAXIMUM RATINGS | T _A = 25 °C, unles | ss otherwise n | oted | | |
|---|-------------------------------|-----------------------------------|--------|--------------|------|
| Parameter | | Symbol | 10 s | Steady State | Unit |
| Drain-Source Voltage | | V _{DS} | 150 | | V |
| Gate-Source Voltage | | V _{GS} | ± 20 | | |
| | T _A = 25 °C | – I _D | 5.0 | 3.5 | |
| Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$ | T _A = 70 °C | | 4.0 | 2.8 | |
| Pulsed Drain Current | | I _{DM} | 50 | | А |
| Avalanche Current | L = 0.1 mH | I _{AS} | 25 | | |
| Continuous Source Current (Diode Conduction) ^a | | ۱ _S | 2.8 | 1.4 | |
| | T _A = 25 °C | PD | 3.1 | 1.56 | W |
| Maximum Power Dissipation ^a | T _A = 70 °C | - FD | 2.0 | 1.0 | vv |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | - 55 1 | to 150 | °C |

| THERMAL RESISTANCE RATINGS | | | | | | |
|--|--------------|--------------------|---------|---------|------|--|
| Parameter | | Symbol | Typical | Maximum | Unit | |
| . | t ≤ 10 s | R _{thJA} | 33 | 40 | | |
| Maximum Junction-to-Ambient ^a | Steady State | ¹ 'thJA | 65 | 80 | °C/W | |
| Maximum Junction-to-Foot (Drain) | Steady State | R _{thJF} | 17 | 21 | | |

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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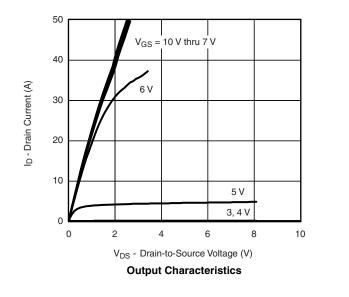
| Parameter | Symbol | Test Conditions | Min. | Тур. | Max. | Unit |
|---|---------------------|---|------|-------|-------|------|
| Static | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$ | 2.0 | | | V |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | | | ± 100 | nA |
| | | V _{DS} = 120 V, V _{GS} = 0 V | | | 1 | μA |
| Zero Gate Voltage Drain Current | IDSS | V_{DS} = 120 V, V_{GS} = 0 V, T_{J} = 55 °C | | | 5 | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$ | 50 | | | А |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}$ | | 0.041 | 0.050 | Ω |
| Forward Transconductance ^a | 9 _{fs} | $V_{DS} = 15 \text{ V}, \text{ I}_{D} = 5 \text{ A}$ | | 18 | | S |
| Diode Forward Voltage ^a | V _{SD} | $I_{S} = 2.8 \text{ A}, V_{GS} = 0 \text{ V}$ | | 0.75 | 1.1 | V |
| Dynamic ^b | | | | | | |
| Total Gate Charge | Qg | | | 30 | 36 | |
| Gate-Source Charge | Q _{gs} | V_{DS} = 75 V, V_{GS} = 10 V, I_{D} = 5 A | | 8.5 | | nC |
| Gate-Drain Charge | Q _{gd} | | | 8.5 | | |
| Gate Resistance | Rg | | 0.2 | 0.85 | 1.2 | Ω |
| Turn-On Delay Time | t _{d(on)} | | | 12 | 18 | |
| Rise Time | t _r | V_{DD} = 75 V, R_L = 15 Ω | | 7 | 11 | |
| Turn-Off Delay Time | t _{d(off)} | $\text{I}_\text{D}\cong \text{5}$ A, V_GEN = 10 V, R_g = 6 Ω | | 22 | 33 | ns |
| Fall Time | t _f | | | 10 | 15 | |
| Source-Drain Reverse Recovery Time | t _{rr} | I _E = 2.8 A, dl/dt = 100 A/μs | | 40 | 70 | |

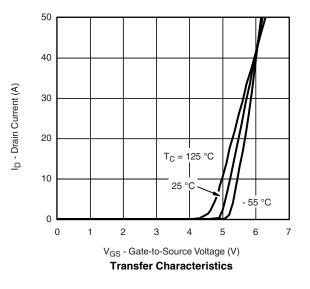
Notes:

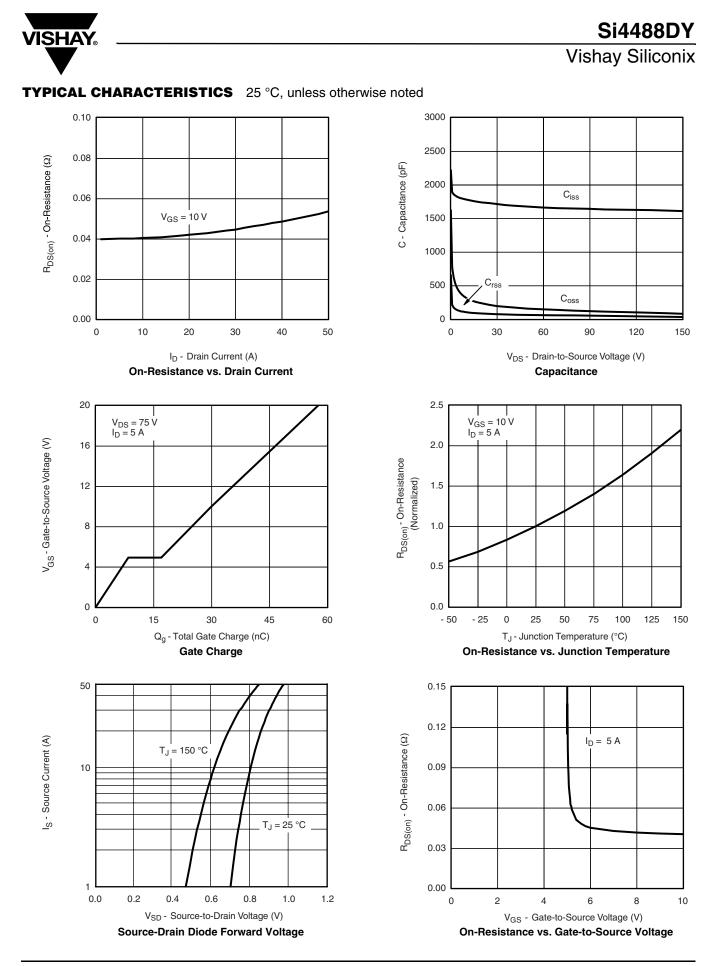
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



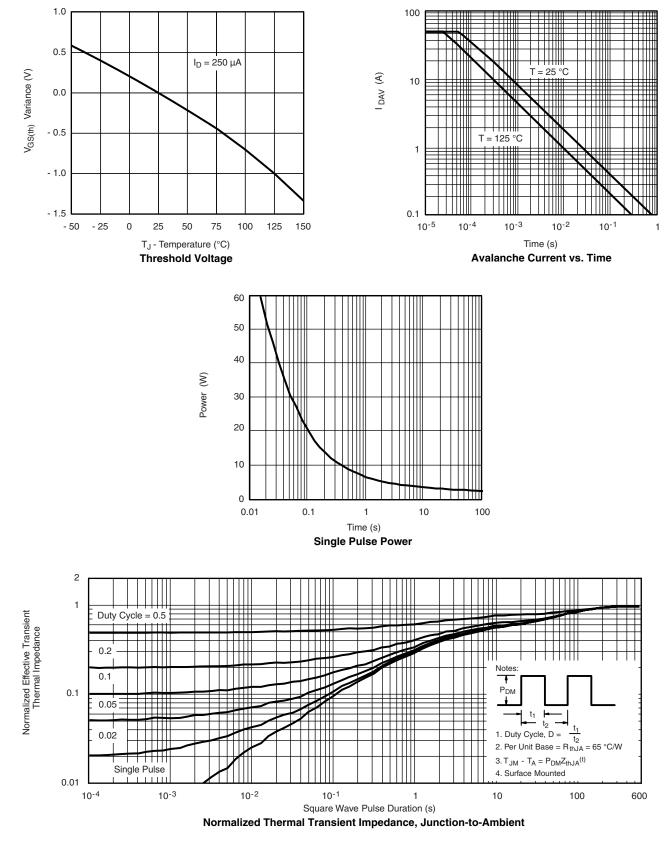




Si4488DY

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

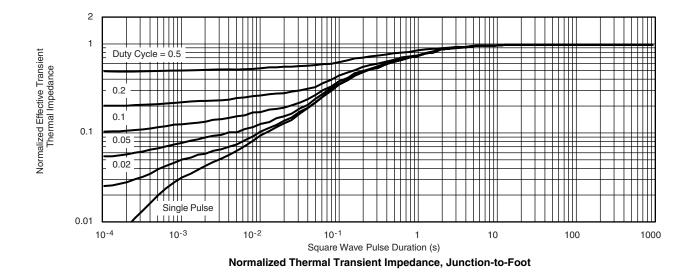


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Si4488DY Vishay Siliconix

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71240.



Package Information

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SOIC (NARROW): 8-LEAD

JEDEC Part Number: MS-012





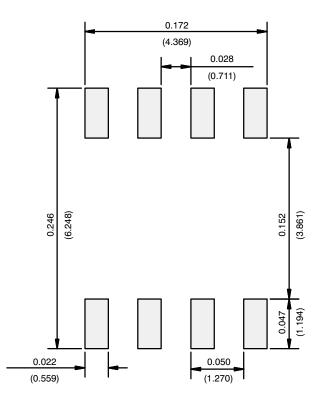
| | MILLIM | IETERS | INCHES | | | |
|---|--------|--------|-----------|-------|--|--|
| DIM | Min | Мах | Min | Max | | |
| A | 1.35 | 1.75 | 0.053 | 0.069 | | |
| A ₁ | 0.10 | 0.20 | 0.004 | 0.008 | | |
| В | 0.35 | 0.51 | 0.014 | 0.020 | | |
| С | 0.19 | 0.25 | 0.0075 | 0.010 | | |
| D | 4.80 | 5.00 | 0.189 | 0.196 | | |
| E | 3.80 | 4.00 | 0.150 | 0.157 | | |
| е | 1.27 | BSC | 0.050 BSC | | | |
| н | 5.80 | 6.20 | 0.228 | 0.244 | | |
| h | 0.25 | 0.50 | 0.010 | 0.020 | | |
| L | 0.50 | 0.93 | 0.020 | 0.037 | | |
| q | 0° | 8° | 0° | 8° | | |
| S | 0.44 | 0.64 | 0.018 | 0.026 | | |
| ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498 | | | | | | |

Application Note 826

Vishay Siliconix



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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